

THREE PHASE DIODE+THYRISTOR

DFA150AA80/160

UL;E76102(M)

SanRex Power Module, **DFA150AA**, is complex isolated module which is designed for rash current circuit.

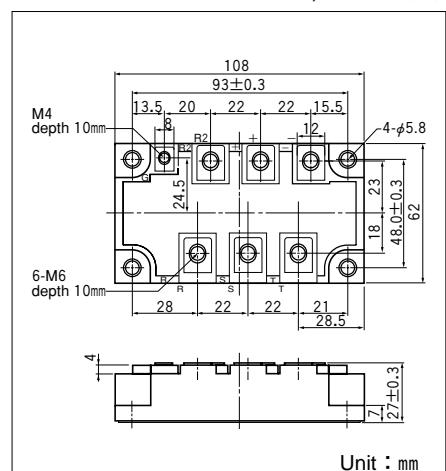
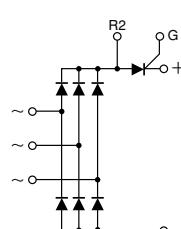
It contains six diodes connected in a three phase bridge configuration, and a thyristor connected to a direct current line.

- This Module is designed very compactly. Because diode module and thyristor put together.

- This Module is also isolated type between electorode terminal and mounting base. So you can put this Module and other one together in a same fin.

(Application)

- Inverter for AC or DC motor control, Current stabilized power supply, Switching power supply.



● DIODE

■ Maximum Ratings

($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Item	Ratings		Unit
		DFA150AA80	DFA150AA160	
V_{RRM}	Repetitive Peak Reverse Voltage	800	1600	V
V_{RSM}	Non-Repetitive Peak Reverse Voltage	960	1700	V

Symbol	Item	Conditions	Ratings	Unit
I_D	Output Current (D.C.)	Three phase full wave, $T_c=93^\circ\text{C}$	150	A
I_{FSM}	Surge forward current	1 cycle, 50/60Hz, peak value, non-repetitive	1460/1600	A
T_j	Operating Junction Temperature		-40 to +150	$^\circ\text{C}$
T_{stg}	Storage Temperature		-40 to +125	$^\circ\text{C}$
V_{iso}	Isolation Breakdown Voltage (R.M.S.)	A.C. 1minute	2500	V
Mounting Torque	Mounting (M5)	Recommended Value 1.5-2.5 (15-25)	2.7 (28)	$\text{N}\cdot\text{m}$ (kgf·cm)
	Terminal (M6)	Recommended Value 2.5-3.9 (25-40)	4.7 (48)	
	Terminal (M4)	Recommended Value 1.0-1.4 (10-14)	1.5 (15)	
Mass	Typical Value		460	g

■ Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
I_{RRM}	Repetitive Peak Reverse Current,max.	$T_j=150^\circ\text{C}$, $V_R=V_{RRM}$	15	mA
V_{FM}	Forward Voltage Drop,max.	$I_F=150\text{A}$, Inst. measurement	1.35	V
$R_{th(j-c)}$	Thermal Impedance, max.	Junction to Case (TOTAL)	0.14	$^\circ\text{C}/\text{W}$
$R_{th(c-f)}$	Thermal Impedance, max.	Case to fin	0.07	$^\circ\text{C}/\text{W}$

● THYRISTOR

■ Maximum Ratings

($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Item	Ratings		Unit
		DFA150AA80	DFA150AA160	
V_{RRM}	Repetitive Peak Reverse Voltage	800	1600	V
V_{RSM}	Non-Repetitive Peak Reverse Voltage	960	1700	V
V_{DRM}	Repetitive Peak off-State Voltage	800	1600	V

Symbol	Item	Conditions	Ratings	Unit
$I_{T(AV)}$	Average On-State Current	Singl phase half wave. 180° conduction, $T_c=93^\circ\text{C}$	150	A
I_{TSM}	Surge On-State Current	1 cycle, 50/60Hz, peak value, non-repetitive	1460/1600	A
I^2t	I^2t (for fusing)		10670	A^2s
di/dt	Critical Rate of Rise of On-State Current	$I_G=100\text{mA}$, $V_D=\frac{1}{2}V_{DRM}$, $di/dt=0.1\text{A}/\mu\text{s}$	150	$\text{A}/\mu\text{s}$
V_{iso}	Isolation Breakdown Voltage (R.M.S.)	A.C. 1minute	2500	V
T_j	Operating Junction Temperature		-40 to +135	$^\circ\text{C}$
T_{stg}	Storage Temperature		-40 to +125	$^\circ\text{C}$
Mounting Torque	Mounting (M5)	Recommended Value 1.5-2.5 (15-25)	2.7 (28)	$\text{N}\cdot\text{m}$ (kgf·cm)
	Terminal (M6)	Recommended Value 2.5-3.9 (25-40)	4.7 (48)	
	Terminal (M4)	Recommended Value 1.0-1.4 (10-14)	1.5 (15)	
Mass		Typical Value	460	g

■ Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
I_{DRM}	Repetitive Peak Off-State Current,max.	$T_j=135^\circ\text{C}$, $V_D=V_{DRM}$	100	mA
I_{RRM}	Repetitive Peak Reverse Current,max.	$T_j=135^\circ\text{C}$, $V_D=V_{RRM}$	100	mA
V_{TM}	Peak On-State Voltage,max.	$T_j=25^\circ\text{C}$, $I_{TM}=150\text{A}$, Inst. measurement	1.35	V
I_{GT}	Gate Trigger Current,max.	$T_j=25^\circ\text{C}$, $V_D=6\text{V}$, $I_T=1\text{A}$	70	mA
V_{GT}	Gate Trigger Voltage,max.	$T_j=25^\circ\text{C}$, $V_D=6\text{V}$, $I_T=1\text{A}$	3	V
dv/dt	Critical Rate of Rise of Off-State Voltage,min.	$T_j=125^\circ\text{C}$, $V_D=\frac{2}{3}V_{DRM}$	500	$\text{V}/\mu\text{s}$
$R_{th(j-c)}$	Thermal Impedance, max.	Junction to Case	0.21	$^\circ\text{C}/\text{W}$
$R_{th(c-f)}$	Thermal Impedance, max.	Case to fin	0.07	$^\circ\text{C}/\text{W}$

